

### General Description

The MAX354/MAX355 fault-protected multiplexers (muxes) use a series N-channel, P-channel, N-channel structure that protects the devices from overvoltage up to 40V beyond the supply rails during power-up, power-down, and fault conditions. The MAX354/MAX355 also protect sensitive circuit components against voltages near or beyond the normal supplies.

The MAX354 single 8-channel mux and the MAX355 dual 4-channel mux protect analog signals while operating from a single 4.5V to 36V supply or  $\pm$ 4.5V to  $\pm$ 18V dual supplies. These muxes have 350 $\Omega$  on-resistance and can be used for demultiplexing as well as multiplexing. Input leakage current is less than 0.5nA at  $\pm$ 25°C and less than 5nA at  $\pm$ 85°C.

All digital inputs have 0.8V and 2.4V logic thresholds, ensuring both TTL and CMOS logic compatibility without pull-up resistors. Break-before-make operation is guaranteed and power consumption is less than 1.5mW.

### **Applications**

Data-Acquisition Systems Industrial and Process Control Avionics ATE Equipment Signal Routing Redundant/Backup Systems

#### \_Features

- ♦ 350Ω Max On-Resistance
- Improved 2nd Source for MAX358/MAX359 and DG458/DG459
- Pin Compatible with ADG508F/ADG509F
- ♦ All Switches Off with Supplies Off
- On Switch Turns Off with Overvoltage
- Output Clamps at 1.5V Below Supply Rails
- ♦ 0.5nA Max Input Leakage at +25°C (5nA at +85°C)
- No Power-Up Sequencing Required
- ♦ TTL and CMOS-Logic Compatibility

#### \_Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX354CPE	0°C to +70°C	16 Plastic DIP
MAX354CWE	0°C to +70°C	16 Wide SO
MAX354C/D	0°C to +70°C	Dice*
MAX354EPE	-40°C to +85°C	16 Plastic DIP
MAX354EWE	-40°C to +85°C	16 Wide SO
MAX354MJE	-55°C to +125°C	16 CERDIP**
MAX355CPE	0°C to +70°C	16 Plastic DIP
MAX355CWE	0°C to +70°C	16 Wide SO
MAX355C/D	0°C to +70°C	Dice*
MAX355EPE	-40°C to +85°C	16 Plastic DIP
MAX355EWE	-40°C to +85°C	16 Wide SO
MAX355MJE	-55°C to +125°C	16 CERDIP**

\* Dice are tested at  $T_A = +25^{\circ}C$  only.

#### Pin Configurations



#### M/X/M

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Contact factory for availability.

### **ABSOLUTE MAXIMUM RATINGS**

(Voltages referenced to GND, unless otherwise noted.)

(Tokageo Fororona to Orto) anioco o tro	moornotoun
V+	0.3V to +44V
V	+0.3V to -44V
V+ to V	0.3V to +44V
Digital Inputs(V+	+ 0.3V) to (V 0.3V)
Input Overvoltage with Mux Power On	
V+ = +15V	
V- = -15V	25V
Input Overvoltage with Mux Power Off	
V + = 0V	+40V
V- = 0V	40V
Continuous Current into Any Terminal	±30mA

Peak Current into Any Terminal	
Plastic DIP (derate 10.53mW/°C above +70°C)	/
Wide SO (derate 9.52mW/°C above +70°C) 762mW	!
CERDIP (derate 10.00mW/°C above +70°C)800mW	1
Operating Temperature Ranges	
MAX35_C0°C to +70°C	
MAX35_E40°C to +85°C	
MAX35_M55°C to +125°C	
Storage Temperature Range65°C to +150°C	
Lead Temperature (soldering, 10sec) +300°C	

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS**

(V+ = +15V, V- = -15V, GND = 0V, VAH = VENH = 2.4V, VAL = VENL = 0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP	MAX	UNITS	
SWITCH		1				1			1
Analog Signal Range		(Note 1) V+ = +15V, V- = -15V (Note 1)			(V+ - 40)		(V- + 40)	V	
Fault-Free Analog Signal Range	V <sub>COM</sub> , V <sub>NO</sub>					-12		12	V
				$T_A = +25^{\circ}C$			285	350	
On-Resistance (Note 2)	RON	$I_{NO} = 1.0 \text{mA}, V_{CON}$	$I = \pm 10V$	T <sub>A</sub> = T <sub>MIN</sub>	C, E			450	Ω
				to T <sub>MAX</sub>	М			500	
On-Resistance Matching	ΔR <sub>ON</sub>	INO = 1.0mA, VCON	1 = ±10V	$T_A = +25^{\circ}C$			7	12	Ω
Between Channels	ARON	(Note 3)		$T_A = T_{MIN}$ to	Т <sub>МАХ</sub>			15	52
NO-Off Leakage Current (Note 4)		$\begin{array}{l} V_{COM}=\ \mp 10V,\\ V_{NO}=\ \pm 10V,\\ V_{EN}=\ 0V \end{array}$		$T_A = +25^{\circ}C$		-0.5	0.01	0.5	
	I <sub>NO(OFF)</sub>			T <sub>A</sub> = T <sub>MIN</sub>	C, E	-5.0		5.0	nA
				to T <sub>MAX</sub> M	М	-50		50	
		$\label{eq:VCOM} \begin{array}{c} V_{COM} = \mp 10V, \\ V_{NO} = \pm 10V, \\ V_{EN} = 0V \end{array} \hspace{1.5cm} \begin{tabular}{l} \label{eq:VCOM} \end{array}$		$T_A = +25^{\circ}C$		-0.5	0.02	0.5	
			MAX354	T <sub>A</sub> = T <sub>MIN</sub>	C, E	-25		25	
COM-Off Leakage Current				to T <sub>MAX</sub> N	М	-100		100	1
(Note 4)	ICOM(OFF)	$\label{eq:VCOM} \begin{array}{l} V_{COM} = \pm 10V, \\ V_{NO} = \mp 10V, \\ V_{EN} = 0V \end{array} \hspace{1.5cm} \text{MAX355}$		$T_A = +25^{\circ}C$		-0.5	0.02	0.5	nA
			T <sub>A</sub> = T <sub>MIN</sub>	C, E	-15		15	1	
				to T <sub>MAX</sub>	М	-50		50	
				$T_A = +25^{\circ}C$		-0.5	0.02	0.5	
COM-On Leakage Current		$V_{COM} = \pm 10V_{c}$	MAX354	T <sub>A</sub> = T <sub>MIN</sub>	С, Е	-30		30	1
		$V_{\rm NO} = \pm 10V$ ,		to T <sub>MAX</sub>	М	-200		200	nA
(Note 4)	ICOM(ON)	sequence each		$T_A = +25^{\circ}C$		-0.5	0.02	0.5	1 114
		switch on MA	MAX355	$T_A = T_{MIN}$	С, Е	-15		15	
				to T <sub>MAX</sub>	М	-100		100	

**ELECTRICAL CHARACTERISTICS (continued)** (V+ = +15V, V- = -15V, GND = 0V, V<sub>AH</sub> = V<sub>ENH</sub> = 2.4V, V<sub>AL</sub> = V<sub>ENL</sub> = 0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
FAULT	1			1				
Output Leakage Current		$V_{D} = 0V$ ,	$T_A = +25^{\circ}C$	-5	0.01	5	nA	
(with Overvoltage)		analog overvoltage = $\pm 33V$	$T_A = T_{MIN}$ to $T_{MAX}$	-2		2	μA	
Input Leakage Current			$T_A = +25^{\circ}C$	-0.1	0.001	0.1		
(with Overvoltage)		$V_{IN} = \pm 25V, V_O = \pm 10V$	$T_A = T_{MIN}$ to $T_{MAX}$	-2		2	- μΑ	
Input Leakage Current		$V_{IN} = \pm 25V$ , $V_{EN} = V_O = 0V$ ,	$T_A = +25^{\circ}C$	-0.1	0.001	0.1		
(with Power Supplies Off)		$V_{A0} = V_{A1} = V_{A2} = 0V \text{ or } 5V$	$T_A = T_{MIN}$ to $T_{MAX}$	-2		2	- μΑ	
DIGITAL LOGIC INPUT								
Logic High Input Voltage	V <sub>A_H</sub> , V <sub>ENH</sub>		$T_A = T_{MIN}$ to $T_{MAX}$	2.4			V	
Logic Low Input Voltage	Va_L, Venl		$T_A = T_{MIN}$ to $T_{MAX}$			0.8	V	
Input Current with		$V_A = V_{EN} = 2.4V$	$T_A = +25^{\circ}C$	-1		1	– μΑ	
Input Voltage High		VA - VEN - 2.4V	$T_A = T_{MIN}$ to $T_{MAX}$	-5		5	μΑ	
Input Current with	IA L, IENL	VA = V <sub>EN</sub> = 0.8V	$T_A = +25^{\circ}C$	-1		1	- μΑ	
Input Voltage Low			$T_A = T_{MIN}$ to $T_{MAX}$	-5		5		
SUPPLY	1							
Power-Supply Range			-	±4.5		±18	V	
Positive Supply Current	l+	$V_{EN} = V_A = 5V$	$T_A = +25^{\circ}C$	-300		300	μΑ	
			$T_A = T_{MIN}$ to $T_{MAX}$	-500		500		
Negative Supply Current I-		$V_{EN} = V_A = 0V$	$T_A = +25^{\circ}C$	-1 -100		1 100	μΑ	
DYNAMIC			$T_A = T_{MIN}$ to $T_{MAX}$	-100		100		
DTNAMIC			$T_A = +25^{\circ}C$		180	250		
Transition Time	<b>t</b> TRANS	Figure1	$T_A = +25 \text{ C}$ $T_A = T_{MIN} \text{ to } T_{MAX}$		160	400	ns	
			$T_A = +25^{\circ}C$		160	250	-	
Enable Turn-On Time	ton(en)	Figure 2	$T_A = T_{MIN}$ to $T_{MAX}$		100	400	ns	
			$T_{A} = +25^{\circ}C$		80	200		
Enable Turn-Off Time	toff(en)	Figure 2	$T_A = T_{MIN}$ to $T_{MAX}$		00	300	ns	
Break-Before-Make Interval	topen	Figure 3	$T_A = +25^{\circ}C$	50	100		ns	
		$C_1 = 10$ nF, $V_S = 0$ V, $R_S = 0$ Ω,						
Charge Injection	V <sub>CTE</sub>	$G_L = 101P, VS = 0V, RS = 0S2,$ Figure 4	$T_A = +25^{\circ}C$		80		рС	
Off Isolation	V <sub>ISO</sub>	$\label{eq:VEN} \begin{split} V_{EN} &= 0V,  R_L = 1k\Omega,  f = 100 kHz, \\ Figure 5 \end{split}$	$T_A = +25^{\circ}C$		100		dB	
Crosstalk Between Channels	V <sub>CT</sub>	$\label{eq:VEN} \begin{array}{l} V_{EN}=2.4V,f=100kHz,\\ V_{GEN}=1V_{p\text{-}p},R_L=1k\Omega,\\ Figure~6 \end{array}$	$T_A = +25^{\circ}C$		92		dB	
Logic Input Capacitance	CIN	f = 1MHz, Figure 7	$T_A = +25^{\circ}C$		2.5		pF	
NO-Off Capacitance	C <sub>NO(OFF)</sub>	$f = 1MHz$ , $V_{EN} = V_D = 0V$	$T_A = +25^{\circ}C$		1.6		рF	

#### ELECTRICAL CHARACTERISTICS (continued)

(V+ = +15V, V- = -15V, GND = 0V, VAH = VENH = 2.4V, VAL = VENL = 0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS		
DYNAMIC (cont'd)									
COM-Off Capacitance		f = 1MHz, Figure 7, $V_{EN} = V_D = 0V$	MAX354	$-T_{A} = +25^{\circ}C$		11		- pF	
	CCOM(OFF)	$V_{EN} = V_D = 0V$	MAX355			5			
COM-On Capacitance	Coorteon	f = 1MHz, Figure 7,	MAX354	$-T_{A} = +25^{\circ}C$		28		– pF	
	CCOM(ON)	$V_{EN} = V_D = 0V$	MAX355			14			
Setting Time (Note 5)	terrr	0.1%	T <sub>A</sub> = +25°C			1		– μs	
	tSETT	0.01%				2.5			

Note 1: When the analog signal exceeds +13.5V or -13.5V, the blocking action of Maxim's gate structure goes into operation. Only leakage currents flow, and the channel on-resistance rises to infinity (see Typical Operating Characteristics).

Note 2: Electrical characteristics such as on-resistance will change when power supplies other than ±15V are used.

Note 3:  $\Delta R_{ON} = R_{ON}(MAX) - R_{ON}(MIN)$ 

 $(T_A = +25^{\circ}C, unless otherwise noted.)$ 

Note 4: Leakage parameters are 100% tested at maximum rated hot operating temperature, and guaranteed by correlation at +25°C. Note 5: Guaranteed by design.

### Typical Operating Characteristics



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### Typical Operating Characteristics (continued)

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$ 





### \_Pin Description

Р	IN		FUNCTION
MAX354	MAX355	NAME	FUNCTION
1, 15, 16	_	A0, A2, A1	Address Logic Inputs
_	1, 16	A0, A1	Address Logic Inputs
2	2	EN	Enable Logic Input. See truth tables.
3	3	V-	Negative Supply Voltage Input. Connect to GND for single-supply operation.
4-7	_	NO1-NO4	Analog Inputs—bidirectional
_	4–7	NO1A-NO4A	Analog Inputs—bidirectional "A" switch
8		СОМ	Analog Output-bidirectional
_	8, 9	COMA, COMB	Analog Outputs-bidirectional
9–12	_	NO8-NO5	Analog Inputs—bidirectional
_	10–13	NO4B-NO1B	Analog Inputs—bidirectional "B" switch
13	14	V+	Positive Supply Voltage Input
14	15	GND	Ground

Note: Analog inputs and outputs are electrically identical and completely interchangeable.



Figure 1. Transition Time



M/IXI/M

Figure 2. Enable Switching Time

MAX354/MAX355



### \_Test Circuits/Timing Diagrams (continued)

Figure 3. Break-Before-Make Interval



Figure 4. Charge Injection

MAX354/MAX355





Figure 5. Off Isolation



Figure 7. NO/COM Capacitance

### Detailed Description

#### **Fault-Protection Circuitry**

Maxim's MAX354/MAX355 are fully fault protected for continuous input voltages up to ±40V, whether or not the V+ and V- power supplies are present. These devices use a "series FET" protection scheme that not only protects the multiplexer output from overvoltage, but also limits the input current to sub-microamp levels. When signal voltages exceed or are within approximately 1.5V of the supply rails, on-resistance increases. This greater on-resistance limits fault currents and output voltage, protecting sensitive circuits and components. The protected output clamps at approximately



Figure 6. Crosstalk

1.5V below the supply rails and maintains the correct polarity. There are no glitches or polarity reversals going into or coming out of a fault condition.

Figures 8 and 9 show how the series FET circuit protects against overvoltage conditions. When power is off, the gates of all three FETs are at ground. With a -25V input, N-channel FET Q1 is turned on by the +25V gate-tosource voltage. The P-channel device (Q2), however, has +25V VGS and is turned off, thereby preventing the input signal from reaching the output. If the input voltage is +25V, Q1 has a negative VGS, which turns it off. Similarly, only sub-microamp leakage currents can flow from the output back to the input, since any voltage will turn off either Q1 or Q2.



Figure 10 shows the condition of an off channel with V+ and V- present. As with Figures 8 and 9, either an Nchannel or a P-channel device will be off for any input voltage from -40V to +40V. The leakage current with negative overvoltages will immediately drop to a few nanoamps at +25°C. For positive overvoltages, that fault current will initially be 10 $\mu$ A or 20 $\mu$ A, decaying over a few seconds to the nanoamp level. The time constant of this decay is caused by the discharge of stored charge from internal nodes and does not compromise the fault-protection scheme.

Figure 11 shows the condition of the on channel with V+ and V- present. With input voltages less than  $\pm$ 10V, all three FETs are on and the input signal appears at the output. If the input voltage exceeds V+ minus the N-channel threshold voltage (VTN), the N-channel FET will turn off. For voltages more negative than V- minus the P-channel threshold (VTP), the P-channel device will turn off. Since VTN is typically 1.5V and VTP is typically 3V, the multiplexer's output swing is limited to about -12V to +13.5V with  $\pm$ 15V supplies.







Figure 10. -25V Overvoltage on an Off Channel with Multiplexer Power Supply On



#### Switching Characteristics and Charge Injection

Table 1 shows typical charge injection levels versus power-supply voltages and analog input voltage. The charge injection that occurs during switching creates a voltage transient whose magnitude is inversely proportional to the capacitance on the multiplexer output.

#### Table 1. MAX354 Charge Injection

Supply Voltage	Analog Input Level	Injected Charge
±5V	+2V 0V -2V	52pC 35pC 16pC
±10V	+ 5V OV -5V	105pC 65pC 25pC
±15V	+10V 0V -10V	180pC 80pC 15pC

Test Conditions:  $C_L$ , = 1000pF on mux output; the tabulated analog input level is applied to channel 1; channels 2–8 inputs are open circuited. EN = +5V,  $V_{A1} = V_{A2} = 0V$ ,  $V_O$  is toggled at a 2kHz rate between 0V and 3V. +100pC of charge creates a +100mV step when injected into a 1000pF load capacitance.



Figure 9. +25V Overvoltage with Multiplexer Power Off



Figure 11. +25V Overvoltage Input to the On Channel

The channel-to-channel switching time is typically 180ns, with about 100ns of break-before-make delay. This 100ns break-before-make delay prevents the input-to-input short that would occur if two input channels were simultaneously connected to the output. In a typical data acquisition system, the dominant delay is not the switching time of the multiplexer, but is the settling time of the amplifiers and S/H. Another limiting factor is the RC time constant of the multiplexer RON plus the signal source impedance multiplied by the load capacitance on the output of the multiplexer. Even with low signal source impedances, 100pF of capacitance on the multiplexer output will approximately double the settling time to 0.01% accuracy.

#### Operation with Supply Voltages Other than ±15V

The main effect of supply voltages other than  $\pm 15V$  is the reduction in output signal range. The MAX354 limits the output voltage to about 1.5V below V+ and about 3V above V-. In other words, the output swing is limited to  $\pm 3.5V$  to  $\pm 2V$  when operating from  $\pm 5V$ . The *Typical Operating Characteristics* show R<sub>ON</sub> for  $\pm 15V$  and  $\pm 5V$ power supplies. Maxim tests and guarantees the MAX354/MAX355 for operation from  $\pm 4.5V$  to  $\pm 18V$ supplies. The switching delays are increased by about a factor of 2 at  $\pm 5V$ , but break-before-make action is preserved.

The MAX354/MAX355 can operate with a single +4.5V to +30V supply, as well as asymmetrical power supplies such as +15V and -5V. The digital threshold remains approximately 1.6V above the GND pin, and the analog characteristics, such as  $R_{ON}$ , are determined by the total voltage difference between V+ and V-. Connect V- to 0V when operating with a +4.5V to +30V single supply.

The MAX354 digital threshold is relatively independent of the power-supply voltages, going from 1.6V typical when V+ is 15V to 1.5V typical when V+ is 5V. This means that the MAX354/MAX355 operate with standard TTL-logic levels, even with  $\pm$ 5V power supplies. In all cases, the threshold of the enable (EN) pin is the same as the other logic inputs.

#### **Digital Interface Levels**

The typical digital threshold of both the address lines and the enable pin is 1.6V, with a temperature coefficient of about  $-3mV/^{\circ}C$ . This ensures compatibility with 0.8V to 2.4V TTL-logic swings over the entire temperature range. The digital threshold is relatively independent of the supply voltages, moving from 1.6V typical to 1.5V typical as the power supplies are reduced from ±15V to ±5V. In all cases, the digital threshold is referenced to the GND pin.

The digital inputs can also be driven with CMOS-logic levels swinging from either V+ to V- or from V+ to ground. The digital input current is just a few nanoamps of leakage at all input voltage levels, with a guaranteed maximum of  $1\mu$ A.

#### **Operation as a Demultiplexer**

The MAX354/MAX355 function as demultiplexers where the input is applied to the output pin, and the input pins are used as outputs. The MAX354/MAX355 provide both break-before-make action and full fault protection when operated as demultiplexers, unlike earlier generations of fault-protected muxes.

#### Channel-to-Channel Crosstalk, Off-Isolation, and Digital Feedthrough

At DC and low frequencies the channel-to-channel crosstalk is caused by variations in output leakage currents as the off-channel input voltages are varied. The MAX354 output leakage varies only a few picoamps as all seven off inputs are toggled from -10V to +10V. The output voltage change depends on the impedance level at the MAX354 output, which is RON plus the input signal source resistance in most cases, since the load driven by the MAX354 is usually high impedance. For a signal source impedance of  $10k\Omega$  or lower, the DC crosstalk exceeds 120dB.

Tables 2a and 2b show typical AC crosstalk and offisolation performance. Digital feedthrough is masked by the analog charge injection when the output is enabled. When the output is disabled, the digital feedthrough is virtually unmeasureable, since the digital pins are physically isolated from the analog section by the GND and V- pins. The ground plane formed by these lines is continued onto the MAX354/MAX355 die to provide over 100dB isolation between the digital and analog sections.

# Table 2a. Typical Off-Isolation RejectionRatio

Frequency	100kHz	1MHz
One Channel Driven	100dB	80dB

Test Conditions: VIN = 20Vp-p at the tabulated frequency,  $R_L$  = 1.5k  $\!\Omega$  between OUT and ground, EN = 0V.

## $V_{ISO} = 20 \log \frac{20 V p - p}{V_{OUT} (p - p)}$

### Table 2b. Typical Crosstalk Rejection Ratio

Frequency	100kHz	1MHz
$R_L = 1.5 k\Omega$	92dB	72dB
$R_L = 10k\Omega$	76dB	56dB

Test Conditions: Specified R<sub>L</sub> connected from OUT to ground, EN = +5V, A<sub>0</sub> = A<sub>1</sub> = A<sub>2</sub> = +5V (Channel 1 selected). 20Vp-p at the tabulated frequency is applied to Channel 2. All other channels are open circuited. Similar crosstalk rejection can be observed between any two channels.

### Functional Diagrams/Truth Tables





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**MAX354/MAX355** 



TRANSISTOR COUNT: 256 SUBSTRATE CONNECTED TO V+

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